

Continental Device India Limited An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



# PNP SILICON PLANAR TRANSISTORS



## BC177/A/B/C BC178/A/B/C BC179/A/B/C

TO-18 Metal Can Package

## Low Noise General Purpose Audio Amplifiers

#### ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	BC177	BC178	BC179	UNIT	
Collector Emitter Voltage	V <sub>CEO</sub>	45	25	20	V	
Collector Emitter Voltage	V <sub>CES</sub>	50	30	25	V	
Collector Base Voltage	V <sub>CBO</sub>	50	30	25	V	
Emitter Base Voltage	V <sub>EBO</sub>	5.0	5.0	5.0	V	
Collector Current Continuous	lc	200				
Power Dissipation at Ta=25°C	PD	300				
Derate above 25°C		1.72				
Power Dissipation at T <sub>c</sub> =25 <sup>o</sup> C	PD	750				
Derate above 25°C		4.29				
Operating and Storage Junction Temperature Range	T <sub>j</sub> , T <sub>stg</sub>	- 65 to +200				

### THERMAL CHARACTERISTICS

Junction to Ambient in free air	R <sub>th (j-a)</sub>	583	°C/W
Junction to Case	R <sub>th (j-c)</sub>	233	°C/W

#### ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless specified otherwise )

DESCRIPTION	SYMBOL	TEST CONDITION	BC177	BC178	BC179	UNIT
Collector Base Voltage	V <sub>CBO</sub>	Ic=10μΑ, I <sub>E=</sub> 0	>50	>30	>25	V
Collector Emitter Voltage	V <sub>CEO</sub>	I <sub>C</sub> =2mA, I <sub>B=</sub> 0	>45	>25	>20	V
Emitter Base Voltage	V <sub>EBO</sub>	I <sub>E</sub> =10μΑ, I <sub>C</sub> =0	>5	>5	>5	V
Collector Cut off Current	I <sub>CES</sub>	V <sub>CE</sub> =20V, I <sub>E</sub> =0	<100			nA
		$V_{CE}=20V, I_{E}=0, T_{a}=125^{\circ}C$	125°C <4			μA
DC Current Gain	h <sub>FE</sub>	I <sub>C</sub> =2mA, V <sub>CE</sub> =5V				
		BC177		120-460		
		BC178	120-800 180-800			
		BC179				
		A Group	120-220			
		B Group	180-460			
	C Group	380-800				

BC177\_179Rev\_3 040509E

## NPN SILICON PLANAR TRANSISTORS



BC177/A/B/C BC178/A/B/C BC179/A/B/C

TO-18 Metal Can Package

### ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector Emitter Saturation Voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA			0.20	V
		Ic=100mA, I <sub>B</sub> =5mA			0.60	V
Base Emitter Saturation Voltage	V <sub>BE (sat)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA			0.80	V
		I <sub>C</sub> =100mA, I <sub>B</sub> =5mA		0.9		V
Base Emitter on Voltage	V <sub>BE (on)</sub>	Ic=2mA, Vce=5V	0.6		0.75	V
Collector Knee Voltage	V <sub>CE (K)</sub>	$I_{C}{=}10mA,~I_{B}{=}the~value~for~which$ $I_{C}{=}11mA$ at $V_{CE}{=}1V$			0.60	V
Transition frequency	f⊤	I <sub>C</sub> =10mA,V <sub>CE</sub> =5V, f=50MHz	200			MHz
Output Capacitance	C <sub>obo</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz			4.0	pF
Noise Figure	NF	$I_C=0.2mA, V_{CE}=5V, Rg=2K\Omega,$				
		f=30Hz to 15KHz BC179			4.0	dB
		f=1KHz, F=200Hz, BC179			4.0	dB
		BC177/178			10	dB

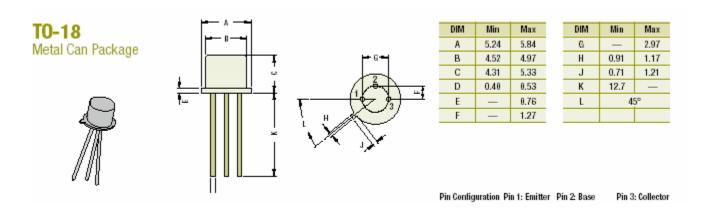
#### SMALL SIGNAL CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Small Signal Current Gain	h <sub>fe</sub>	Ic=2mA, Vce=5V, f=1KHz				
		BC177	120		460	
		BC178	120		800	
		BC179	180		800	
		A Group	120		220	
		B Group	180		460	
		C Group	380		800	
Input Impedance	h <sub>ie</sub>	Ic=2mA, Vce=5V, f=1KHz				
		A Group	1.6		4.5	KΩ
		B Group	3.2		8.5	KΩ
		C Group	6.0		15	KΩ
Output Admittance	h <sub>oe</sub>	I <sub>C</sub> =2mA, V <sub>CE</sub> =5V, f=1KHz				
		A Group			30	μmhos
		B Group			60	μmhos
		C Group			110	μmhos

BC177\_179Rev\_3 040509E

BC177/A/B/C BC178/A/B/C BC179/A/B/C

TO-18 Metal Can Package



Packaging Specifications									
Package / Case Type Packaging Type Std. Packing Inner Carton Outer Carton									
		Qty	Qty	Size L x W x H	Gross Weight	Qty	Size L x W x H	Gross Weight	
				(cm)	(Kg)		(cm)	(Kg)	
Metal Can Packages									
TO-18	Bulk	1,000	5K	19x19x8	1.7	50K	43 x 38 x 34	18.2	

BC177\_179Rev\_3 040509E

TO-18 Metal Can Package

### **Component Disposal Instructions**

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

### Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.

